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# Role of interface on electrical conductivity of carbon nanotube/alumina nanocomposite

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#### **Abstract**

Interface of multiwalled carbon nanotube (MWCNT)/alumina ( $Al_2O_3$ ) nanocomposites have been studied using TEM. At low sintering temperature ( $T_{sin}$ =1500 °C), a 3–5 nm thick amorphous interface region was noticed. Nanocomposite sintered at 1700 °C possessed a well-defined graphene layer coating on matrix grains as the interface between CNT and  $Al_2O_3$ . A mechanism of such layered interface formation has been proposed. No traceable chemical reaction product was observed at the interface even after sintering at 1700 °C. It was noticed that while DC electrical conductivity ( $\sigma_{DC}$ ) of 1500 °C sintered 2.4 vol% MWCNT/ $Al_2O_3$  nanocomposite was only  $\sim$ 0.02 S/m, it raised to  $\sim$ 21 S/m when sintering was done at 1700 °C. Such 10<sup>3</sup> times increase in  $\sigma_{DC}$  of present nanocomposite at a constant CNT loading was not only resulted from the exceptionally high electron mobility of CNT but the well-crystallized graphene interface on insulating type  $Al_2O_3$  grains also significantly contributed in the overall increase of electrical performance of the nanocomposite, especially, when sintering was done at 1700 °C. © 2013 Elsevier Ltd and Techna Group S.r.l. All rights reserved.

Keywords: B. Electron microscopy; B. Interfaces; B. Nanocomposites; C. Electrical conductivity

## 1. Introduction

In composites, optimum interface performance is essential since it decides how effectively applied load (mechanical), electron (electrical/electronic) and phonon (thermal) transfer occurs among its constituents [1]. Therefore, interface characterization is indispensable to establish the exact structure-property relationship in composites. CNT reinforced ceramic matrix nanocomposites viz. CNT/Al<sub>2</sub>O<sub>3</sub>, CNT/Si<sub>3</sub>N<sub>4</sub>, CNT/ZrO<sub>2</sub>, CNT/SiC, CNT/SiO<sub>2</sub>-ZnO are not exception in this regard [2–6]. Although, many reports are available on property evaluation of the most ancient, economic and versatile ceramic i.e. Al<sub>2</sub>O<sub>3</sub> reinforced with CNT [7–13], limited work has been performed on CNT/Al<sub>2</sub>O<sub>3</sub> interface characterization [7–8,13–14]. Further, most of these reports dealt with structural integrity of CNT in sintered nanocomposites and position of nanotubes in matrix phase (i.e. within, outside or at grain boundary

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position). The primary aim of present work was to study the interface/interaction region of pressureless sintered CNT/Al<sub>2</sub>O<sub>3</sub> nanocomposites and changes in interface nature with increasing  $T_{sin}$  using TEM. Finally, correlation between observed CNT/Al<sub>2</sub>O<sub>3</sub> interface and  $\sigma_{DC}$  of present nanocomposites was analyzed.

## 2. Experimental procedures

#### 2.1. Raw material and sample preparation

Multiwalled CNT (MWCNT: Shenzhen NTP, China, > 95 wt% pure) and Al<sub>2</sub>O<sub>3</sub> powder (Almatis, ACC Ltd., India, 99.8 wt% pure) were used as raw materials [12]. The nanocomposite fabrication procedure can be found elsewhere [12]. In brief, nanocomposite powder mixtures were prepared by wet-mixing of as-received dispersed raw materials followed by drying and sieving. Sintering was done in a graphite resistance heating furnace (1000-4560-FP20; Thermal Technology Inc. U.S.A.) under static Argon (Ar: 35–70 kPa) (Table 1).

Table 1
Batch details, sintering schedule, nomenclature and theoretical density of studied specimens.

Batch id	CNT (wt%)	Sintering schedule	Sintered as	Specimen id	TD (g/cc)
A	0.00	1500 °C/2 h./Ar	Pellet	A15	3.970
		1600 °C/2 h/Ar	Pellet	A16	
		1700 °C/2 h/Ar	Pellet	A17	
В	0.07	1500 °C/2 h/Ar	Pellet	B15	3.967
		1600 °C/2 h/Ar	Pellet	B16	
		1700 °C/2 h/Ar	Pellet	B17	
C	0.13	1500 °C/2 h/Ar	Pellet	C15	3.963
		1600 °C/2 h/Ar	Pellet	C16	
		1700 °C/2 h/Ar	Pellet	C17	
D	0.27	1500 °C/2 h/Ar	Pellet	D15	3.957
		1600 °C/2 h/Ar	Pellet	D16	
		1700 °C/2 h/Ar	Pellet	D17	
E	0.54	1500 °C/2 h/Ar	Pellet	E15	3.944
		1600 °C/2 h/Ar	Pellet	E16	
		1700 °C/2 h/Ar	Pellet	E17	
F	1.09	1500 °C/2 h/Ar	Pellet	F15	3.917
		1600 °C/2 h/Ar	Pellet	F16	
		1700 °C/2 h/Ar	Pellet	F17	
G	35.00	1500 °C/2 h/Ar	Powder	G15	2.771
		1600 °C/2 h/Ar	Powder	G16	
		1700 °C/2 h/Ar	Powder	G17	

## 2.2. Interface characterization

For interface observations, sintered nanocomposites were observed through TEMs ( $Tecnai\ G^230ST$  and  $Tecnai\ G^220ST$ ,  $FEI\ Company$ ,  $The\ Netherlands$ ). It may be seen from Table 1 that beside bulk nanocomposites containing 0.07–1.09 wt% CNT (i.e. batch #'A'-'F'), nanocomposite powder containing 35 wt% MWCNT (i.e. batch "G") was also heat-treated at the sintering temperatures. Purpose of using such a high nanotube concentration was to minimize chances of structural damage of CNTs and interface regions in pelletized nanocomposites caused by ultrasonic slicing, dimple grinding and ion-milling steps required for TEM bulk specimen preparation and to raise the probability of finding CNT/Al<sub>2</sub>O<sub>3</sub> interface due to significantly high CNT content.

## 2.3. Electrical property measurement

Room temperature (RT)  $\sigma_{DC}$  of pelletized MWCNT/Al<sub>2</sub>O<sub>3</sub> nanocomposites and pure Al<sub>2</sub>O<sub>3</sub> was measured by standard 2-probe method using a 2400 Sourcemeter, Keithley Instrument Inc., U.S.A. Results were correlated with the nature of interface formed in the nanocomposites.

#### 3. Results and discussions

### 3.1. Physical properties of the sintered specimens

Plot of relative density (RD) values of all the specimens is shown in Fig. 1. The RD values were calculated using the

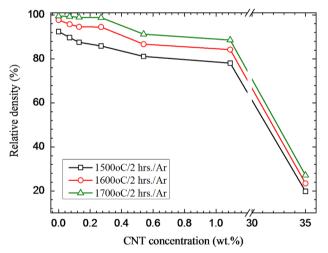


Fig. 1. Physical properties of the studied specimens.

theoretical density (TD) values of corresponding specimens given in Table 1. Theoretical density of each of the specimens were calculated using *Rule of Mixture* taking  $\rho_{Al2O3}$ =3.97 g/cc and  $\rho_{MWCNT}$ =1.775 g/cc [11,13]. Densities of sintered bulk specimens were evaluated using the *Archimedes water immersion* technique and that for specimen 'G' were evaluated by standard Tapping method. Detailed discussion on physical properties and microstructure of present nanocompostes can be found elsewhere [11,13].

#### 3.2. Interface analyses of the sintered specimens

TEM images of as-received MWCNTs indicated presence of tubes of different diameters having partialy alligned graphene layers and apperently smooth external surfaces (Fig. 2(a-b)). However, in certain cases (Fig. 2(b)), a very thin layer was noticed on the externatl wall of CNTs that possibly came from residual amorphous carbon (3-5 wt%) and/or other impurities present in as-received MWCNT [15]. Except Fig. 2(a-b), interested readers can found additional TEM images of asreceived MWCNTs in our earlier communications [15–16]. TEM image of D15 confirmed structural stability of CNT after sintering at 1500 °C for 2 h in Argon (Fig. 3(a)). Bamboo structured CNTs and attachment of nanotubes with Al<sub>2</sub>O<sub>3</sub> grains were also observed (Fig. 3(a)). Interface in D15 had no well-defined crystalline pattern; it was rather amorphous in nature having thickness of 3-5 nm (Fig. 3(b)). Presence of CNT agglomerates at *intergranular* pores was noticed in F17 (Fig. 4(a)). Interestingly, at higher magnification, existence of certain reaction zone was observed in F17 through which CNTs were attached with the matrix grains (Fig. 4(b)). Thus, sintering at 1700 °C possibly helped in formation of a distinct interface in the nanocomposites to hold CNT and Al<sub>2</sub>O<sub>3</sub> grains together and played a significant role in property enhancement of studied specimens [12]. To further confirm this, sintered nanocomposite powder (batch 'G') was studied using TEM. Fig. 5(a) shows that in G15, CNTs were attached with Al<sub>2</sub>O<sub>3</sub> grains by the so-called *pinning* action [8,10,14] and there was no interface formed between filler and matrix. Fig. 5(b) shows side-by-side attachment of CNT and Al<sub>2</sub>O<sub>3</sub> in G15 without any traceable chemical reaction product at the boundary. Similarly, in G16, penetration of survived CNTs in matrix was noticed (Fig. 6(a)). Surprisingly, a graphene layer coating of a few nanometer thicknesses and having interlayer spacing of  $\sim 0.34$ nm was found around the matrix grains after sintering at 1600 °C (Fig. 6(b)). Finally, after sintering at 1700 °C of the nanocomposite powder, TEM study confirmed characteristic existence of the graphene layer encapsulation of the matrix grains that acted as interface between CNT and Al<sub>2</sub>O<sub>3</sub> (Fig. 7 (a–b)). A possible sequence of such layered interface formation in this nanocomposite is shown in Fig. 8. It has been reported that at temperature > 1500 °C in Argon, splitting of external graphene layers of MWCNTs from either highly strained regions or defects is possible [16]. Under high temperature and/or pressure, such deformed/splitted nanotubes are tending to form different caged nano-structures [17]. Further, as reported by Sarkar and Das [15-16], formation of various nano-structures or distinct graphene layers was more favorable

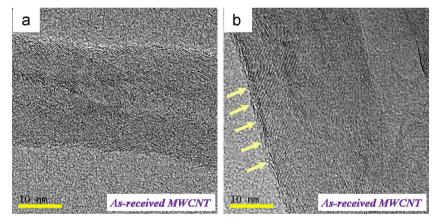


Fig. 2. TEM images of as-received MWCNT showing partially aligned graphene layers (a) in a thin CNT and (b) thick CNT having very thin layer (indicated by pointed arrows) on the external surface possibly of residual amorphous carbon or other impurities; scale bar: 10 nm.

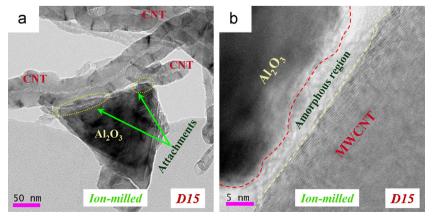


Fig. 3. TEM images of D15 showing: (a) attachment of CNTs with Al<sub>2</sub>O<sub>3</sub> grains; scale bar: 50 nm, and (b) amorphous interface; scale bar: 5 nm.

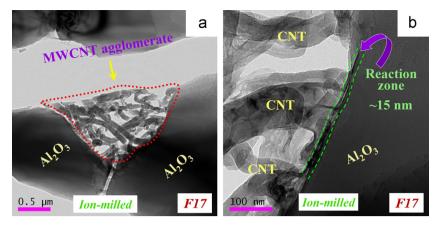


Fig. 4. TEM images of F17 showing (a) presence of nanotube agglomerate at intergranular pore; scale bar: 0.5 μm and (b) interaction zone; scale bar: 100 nm.

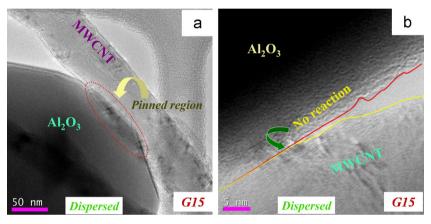


Fig. 5. TEM images of G15 showing (a) pinning of Al<sub>2</sub>O<sub>3</sub> grains by CNT; scale bar: 50 nm and (b) side-by-side attachment of CNT-Al<sub>2</sub>O<sub>3</sub>; scale bar: 5 nm.

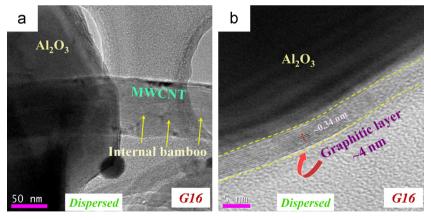


Fig. 6. TEM images of G16 showing (a) penetrated CNT in matrix grain; scale bar: 50 nm, and (b) formation of graphitic layer on Al<sub>2</sub>O<sub>3</sub>; scale bar: 5 nm.

in singlewalled CNTs (SWCNTs) than MWCNTs when exposed to high temperature ( $\sim 1800~^\circ\text{C}$ ) in inert atmosphere. In SWCNT, splitting of only a single graphene layer entirely damaged the tubular morphology and transformed into other polygonal nano-shapes by stacking of such splitted layers from many such SWCNTs at high temperatures ( $\sim 1800~^\circ\text{C}$ ). On contrary, in MWCNTs, due to the presence of interwall *van der Walls* attractive forces and possibly certain cross-linking effects, the splitted layers did not completely detach from the

parent nanotube and formed nano-scale corrugation on the external wall of heat-treated MWCNTs [16]. In present case, pressure on CNTs might arouse from the overall volume shrinkage of consolidating nanocomposites. Thus, once the strained/defective layers splitted from external wall of MWCNTs during sintering they retreated in the opposite direction for strain relaxation and surrounding growing Al<sub>2</sub>O<sub>3</sub> grains squeezed the splitted graphene layers within them and by the action of heat and pressure, the squeezed

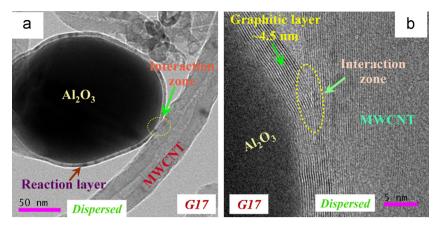


Fig. 7. TEM images of G17 showing (a) attachment of CNTs with Al<sub>2</sub>O<sub>3</sub> grain through graphene layer encapsulation; scale bar: 50 nm and (b) HRTEM image of the layered interface; scale bar: 5 nm.

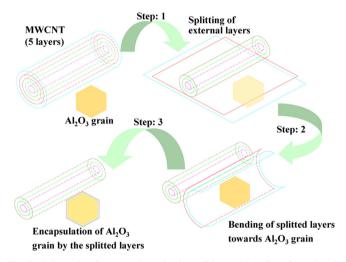


Fig. 8. Schematic of proposed mechanism of layered interface formation in  $CNT/Al_2O_3$  nanocomposites.

layers ultimately deposited on the surface of  $Al_2O_3$  grains to create the thin graphene layer encapsulation. By this process,  $Al_2O_3$  grains attached with a rather narrow diameter CNT through this layer, especially, at higher  $T_{sin}$  (Fig. 8). The graphene encapsulation not only provided an interface between CNT and  $Al_2O_3$ , but also stopped growth of encapsulated  $Al_2O_3$  grains resulting in finer grain size in nanocomposites over pure  $Al_2O_3$  sintered under identical condition. During TEM studies, no Al-O-C compound was detected in these nanocomposites as reported by others [8,13].

## 3.3. Electrical properties of the sintered specimens

 $RT \, \sigma_{DC}$  values of pelletized specimens sintered at three  $T_{sin}s$  are shown in Fig. 9.  $\sigma_{DC}$  of pure  $Al_2O_3$  at RT was taken as  $10^{-12}$  S/m [18]. It may be seen from the figure that increasing CNT content in highly resistive  $Al_2O_3$  rendered significant enhancement in  $\sigma_{DC}$ , especially, at CNT loading  $\geq 0.6$  vol%. Furthermore, with increase in  $T_{sin}$ , the so-called *percolation threshold* i.e. conductive network of CNT was decreased from 1.2 vol% MWCNT loading for 1500 °C sintered specimens to

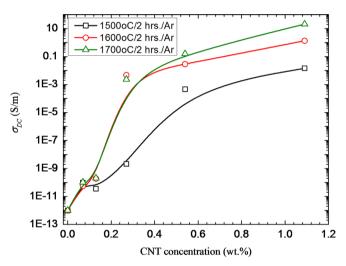


Fig. 9. Plot RT  $\sigma_{DC}$  versus CNT concentration of pelletized nanocomposites.

0.6 vol% MWCNT for 1600° and 1700 °C sintered nanocomposites. Such lowering of percolation threshold on increasing  $T_{sin}$  was aroused due to the fact that at low  $T_{sin}$ , shrinkage of nanocomposites was less and thus, desired interconnected network of highly conducting CNTs was only achieved for specimens containing 1.2 or 2.4 vol% CNT. Since, 1.2 or 2.4 vol% CNT/Al<sub>2</sub>O<sub>3</sub> nanocomposites characteristically contained agglomerated CNTs along the matrix grain boundaries, even at low shrinkage, these specimens exhibited highly conducting nature compared to pure Al<sub>2</sub>O<sub>3</sub>. On the other hand, sintering at higher temperatures (i.e. 1600 or 1700 °C) resulted in further shrinkage of nanocomposites leading to the formation of desired percolating CNT network in nanocomposites containing  $\geq 0.6$  vol% CNT by reducing the spacing among the tubes and ensured enhanced tunneling effect of electrons through individual CNTs or bundles. While an abrupt increase in  $\sigma_{DC}$  from  $\sim 10^{-12}$  S/m for pure Al<sub>2</sub>O<sub>3</sub> to  $10^{-4}$  S/m for E15 specimen was observed among the 1500 °C sintered specimens, among 1600 and 1700 °C sintered specimens, percolation was noticed at 0.6 vol% CNT loading and  $\sigma_{DC}$ changed from  $\sim 10^{-12}$  S/m for pure Al<sub>2</sub>O<sub>3</sub> to  $\sim 10^{-3}$  S/m for the nanocomposite (Fig. 9). The low percolation concentration

(i.e.  $\geq 0.6$  vol% CNT) obtained for present CNT/Al<sub>2</sub>O<sub>3</sub> nano-composites were consistent with the previous reports on CNT/ceramic nanocomposites and was attributed to high aspect ratio of present MWCNTs (83  $\leq$   $l/d \leq$  150), high electrical conductivity  $\approx 1.85 \times 10^3$  S/m and current density ( $10^7$  A/cm²) along tube axis of undamaged MWCNTs [18–25]. Among all the specimens, the highest  $\sigma_{DC}$  at RT was obtained for batch 'F' sintered nanocomposites ( $^{F15}\sigma_{DC}$ =0.0146 S/m;  $^{F16}\sigma_{DC}$ =1.36 S/m and  $^{F17}\sigma_{DC}$ =21 S/m). Now, the question is that why  $\sigma_{DC}$  of F17 was found to be  $10^3$  times higher than that of F15 although both of the specimens contained 2.4 vol% nanotube? The reasons are the following:

- i. Increased densification at higher  $T_{sin}$ , ensured better connectivity among the nanotubes and resulted in higher  $\sigma_{DC}$  at constant CNT loading.
- ii. In a recent communication, Liu et al. [6] reported that reaction between CNT and ZnO helped in effective removal of residual amorphous carbon from the nanotubes and created higher oxygen vacancies in ZnO during sintering of a CNT/SiO<sub>2</sub>-ZnO nanocomposite and drastically enhanced the  $\sigma_{DC}$  of the nanocomposite over pure SiO<sub>2</sub>. In a similar way, in present study high temperature sintering might helped in amorphous carbon removal from MWCNTs and rendered better connectivity among the tubes resulting in increased  $\sigma_{DC}$  of the nanocomposites.
- iii. Formation of a well-crystallized and a few layer thick graphene interface on insulating  $Al_2O_3$  grains at higher  $T_{sin}$  rendered exceptional increase in  $\sigma_{DC}$  to the high temperature ( $\geq 1600~^\circ\text{C}$ ) sintered nanocomposites even at constant CNT loading. This was due to the fact that carrier mobility, current density in graphene nano-ribbons that resembles the interface formed in present nanocomposite can go up to  $2\times 10^5~\text{cm}^2/\text{V-s}$  and  $10^{11}$ – $10^{13}~\text{A/m}^2$  which are comparable or even better than MWCNT [19,26–30]. Since, attachment of reinforcing nanotubes with the graphene interface was found to be much better in 1700  $^\circ\text{C}$  sintered nanocomposites (Fig. 4(b) and clarified in Fig. 7(a and b)),  $\sigma_{DC}$  also increased  $10^3$  times over F15 containing an amorphous interface (Fig. 3(b)).

#### 4. Conclusions

At low  $T_{sin}$ , pressureless sintered CNT/Al<sub>2</sub>O<sub>3</sub> nanocomposite possessed an amorphous interface. Attachment of CNT with Al<sub>2</sub>O<sub>3</sub> grains was primarily a result of *pinning* by nanotubes. At 1700 °C, a thin graphene layer encapsulation was formed on Al<sub>2</sub>O<sub>3</sub> grains that provided a prominent interface between CNT and Al<sub>2</sub>O<sub>3</sub> and helped in grain refining of sintered nanocomposites. The layered encapsulation was formed by splitting of strained/defective external graphene layers of MWCNTs at high  $T_{sin}$  (>1500 °C) followed by bending towards and squeezing by the neighboring Al<sub>2</sub>O<sub>3</sub> grains to form the close structure. The graphene interface in 1700 °C sintered nanocomposites contributed notably in overall increase of  $\sigma_{DC}$  by  $10^3$  times over the low temperature sintered specimens by minimizing the effect of insulating

matrix and providing better connecting path among the nanotubes free from amorphous carbon and other impurities for electron transport.

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#### References

- A.G. Evans, D.B. Marshall, Mechanical behavior of ceramic matrix composites, in: K.S. Mazdiyasni (Ed.), Fiber reinforced Ceramic Composites: Materials, Processing, and Technology, Noyes Publications, Park Ridge, New Jersey, USA, 1990.
- [2] J. Echeberria, N. Rodri'guez, J. Vleugels, K. Vanmeensel, A. Reyes-Rojas, A. Garcia-Reyes, C. Domi'nguez-Rios, A. Aguilar-Elgue'zabal, M.H. Bocanegra-Bernal, Hard and tough carbon nanotube-reinforced zirconia-toughened alumina composites prepared by spark plasma sintering, Carbon 50 (2012) 706–717.
- [3] X. Liu, X. Yin, G. Zheng, Y. Liu, L. Kong, Q. Li, X. Yuan, In-situ formation of carbon nanotubes in pyrolytic carbon–silicon nitride composite ceramics, Ceram. Int. Available online 18 June 2013, http:// dx.doi.org/10.1016/j.ceramint.2013.06.035.
- [4] J. Yi, T. Wang, Z. Xie, W. Xue, Zirconia-based nanocomposite toughened by functionalized multi-wall carbon nanotubes, J. Alloy. Compd. 581 (2013) 452–458.
- [5] J. Hu, S. Dong, X. Zhang, H. Zhou, B. Wu, Z. Wang, P. He, L. Gao, Process and mechanical properties of carbon/carbon-silicon carbide composite reinforced with carbon nanotubes grown in situ, Compos. Part A: Appl. Sci. Manuf. 48 (2013) 73–81.
- [6] Y. Liu, X. Yin, L. Kong, X. Liu, F. Ye, L. Zhang, L. Cheng, Electromagnetic properties of SiO<sub>2</sub> reinforced with both multi-wall carbon nanotubes and ZnO particles, Carbon 64 (2013) 541–544.
- [7] M. Estili, A. Kawasaki, H. Sakamoto, Y. Mekuchi, M. Kuno, T. Tsukada, The homogeneous dispersion of surfactantless, slightly disordered, crystalline, multiwalled carbon nanotubes in α-alumina ceramics for structural reinforcement, Acta Mater. 56 (2008) 4070–4079.
- [8] I. Ahmad, M. Unwin, H. Cao, H. Chen, H. Zhao, A. Kennedy, Y.Q. Zhu, Multi-walled carbon nanotubes reinforced Al<sub>2</sub>O<sub>3</sub> nanocomposites: mechanical properties and interfacial investigations, Compos. Sci. Technol. 70 (2010) 1199–1206.
- [9] K. Lee, C.B. Mo, S.B. Park, S.H. Hong, Mechanical and electrical properties of multiwalled CNT-alumina nanocomposites prepared by a sequential two-step processing of ultrasonic spray pyrolysis and spark plasma sintering, J. Am. Ceram. Soc. 94 (2011) 3774–3779.
- [10] S. Bi, G. Hou, X. Su, Y. Zhang, F. Guo, Mechanical properties and oxidation resistance of α-alumina/multi-walled carbon nanotube composite ceramics, Mater. Sci. Eng. A 528 (2011) 1596–1601.
- [11] S. Sarkar, P.K. Das, Temperature and load dependent mechanical properties of pressureless sintered carbon nanotube/alumina nanocomposites, Mater. Sci. Eng. A 531C (2012) 61–69.
- [12] S. Sarkar, P.K. Das, Microstructure and physicomechanical properties of pressureless sintered multiwalled carbon nanotube/alumina nanocomposites, Ceram. Int. 38 (2012) 423–432.
- [13] S. Sarkar, P.K. Das, Statistical analysis of mechanical properties of pressureless sintered multiwalled carbon nanotube/alumina nanocomposites, Mater. Chem. Phys. 137 (2012) 511–518.
- [14] I. Ahmad, H. Cao, H. Chen, H. Zhao, A. Kennedy, Y.Q. Zhu, Carbon nanotube toughened aluminium oxide nanocomposite, J. Eur. Ceram. Soc. 30 (2010) 865–873.

- [15] S. Sarkar, P.K. Das, Thermal and structural stability of single- and multiwalled carbon nanotubes up to 1800 °C in Argon studied by Raman spectroscopy and transmission electron microscopy, Mater. Res. Bull. 48 (2013) 41–47.
- [16] S. Sarkar, P.K. Das, S. Bysakh, Effect of heat treatment on morphology and thermal decomposition kinetics of multiwalled carbon nanotubes, Mater. Chem. Phys. 125 (2011) 161–167.
- [17] M. Zhang, D.W. He, L. Ji, B.Q. Wei, D.H. Wu, X.Y. Zhang, Y.F. Xu, W. K. Wang, Microstructural changes in carbon nanotubes induced by annealing at high pressure, Carbon 37 (1999) 657–662.
- [18] G.-D. Zhan, A.K. Mukherjee, Carbon nanotube reinforced alumina-based ceramics with novel mechanical, electrical and thermal properties, Int. J. Appl. Ceram. Technol. 1 (2) (2004) 161–171.
- [19] Y. Ando, X. Zhao, H. Shimoyama, G. Sakai, K. Kaneto, Physical properties of multiwalled carbon nanotubes, Int. J. Inorganic Mater. 1 (1999) 77–82.
- [20] K. Ahmad, W. Pan, Dramatic effect of multiwalled carbon nanotubes on the electrical properties of alumina based ceramic nanocomposites, Compos. Sci. Technol. 69 (2009) 1016–1021.
- [21] K. Ahmad, W. Pan, S.-L. Shi, Electrical conductivity and dielectric properties of multiwalled carbon nanotube and alumina composites, Appl. Phys. Lett. 89 (2006) 133122.
- [22] F. Inam, H. Yan, D.D. Jayaseelan, T. Peijs, M.J. Reece, Electrically conductive alumina-carbon nanocomposites prepared by spark plasma sintering, J. Eur. Ceram. Soc. 30 (2010) 153–157.
- [23] K. Lee, C.B. Mo, S.B. Park, S.H. Hong, Mechanical and electrical properties of multiwalled CNT-alumina nanocomposites prepared by a

- sequential two-step processing of ultrasonic spray pyrolysis and spark plasma sintering, J. Am. Cream. Soc. 94 (11) (2012) 3774–3779.
- [24] L. Kumari, T. Zhang, G.H. Du, W.Z. Li, Q.W. Wang, A. Datye, K. H. Wu, Synthesis, microstructure and electrical conductivity of carbon nanotube-alumina nanocomposites, Ceram. Int. 35 (2009) 1775–1781.
- [25] M. Poorteman, M. Traianidis, G. Bister, F. Cambier, Colloidal processing, hot pressing and characterisation of electroconductive MWCNT-alumina composites with compositions near the percolation threshold, J. Eur. Ceram. Soc. 29 (2009) 669–675.
- [26] W.Y. Jang, N.N. Kulkarni, C.K. Shih, Z. Yao, Electrical characterization of individual carbon nanotubes grown in nanoporous anodic alumina templates, Appl. Phys. Lett. 84 (7) (2004) 1177–1179.
- [27] L. Zeng, X.Y. Liu, G. Du, J.F. Kang, R.Q. Han, Evaluation of mobility in graphene nanoribbons including line edge roughness scattering, In: SISPAD 2009, San Diego, CA, 2009, pp. 1–4.
- [28] A. Behnam, A.S. Lyons, M.-H. Bae, E.K. Chow, S. Islam, C. M. Neumann, E. Pop, Transport in nanoribbon interconnects obtained from graphene grown by chemical vapor deposition, Nano Lett. 12 (2012) 4424–4430.
- [29] K.-J. Lee, A.P. Chandrakasan, J. Kong, Breakdown current density of CVD-grown multilayer graphene interconnects, IEEE Electron. Device Lett. 32 (2011) 557–559.
- [30] K.S. Novoselov, V.I. Falko, L. Colombo, P.R. Gellert, M.G. Schwab, K. Kim, A roadmap for graphene, Nature 490 (2012) 192–200.